

# Electron density of states and mobility in dilute GaAs:N

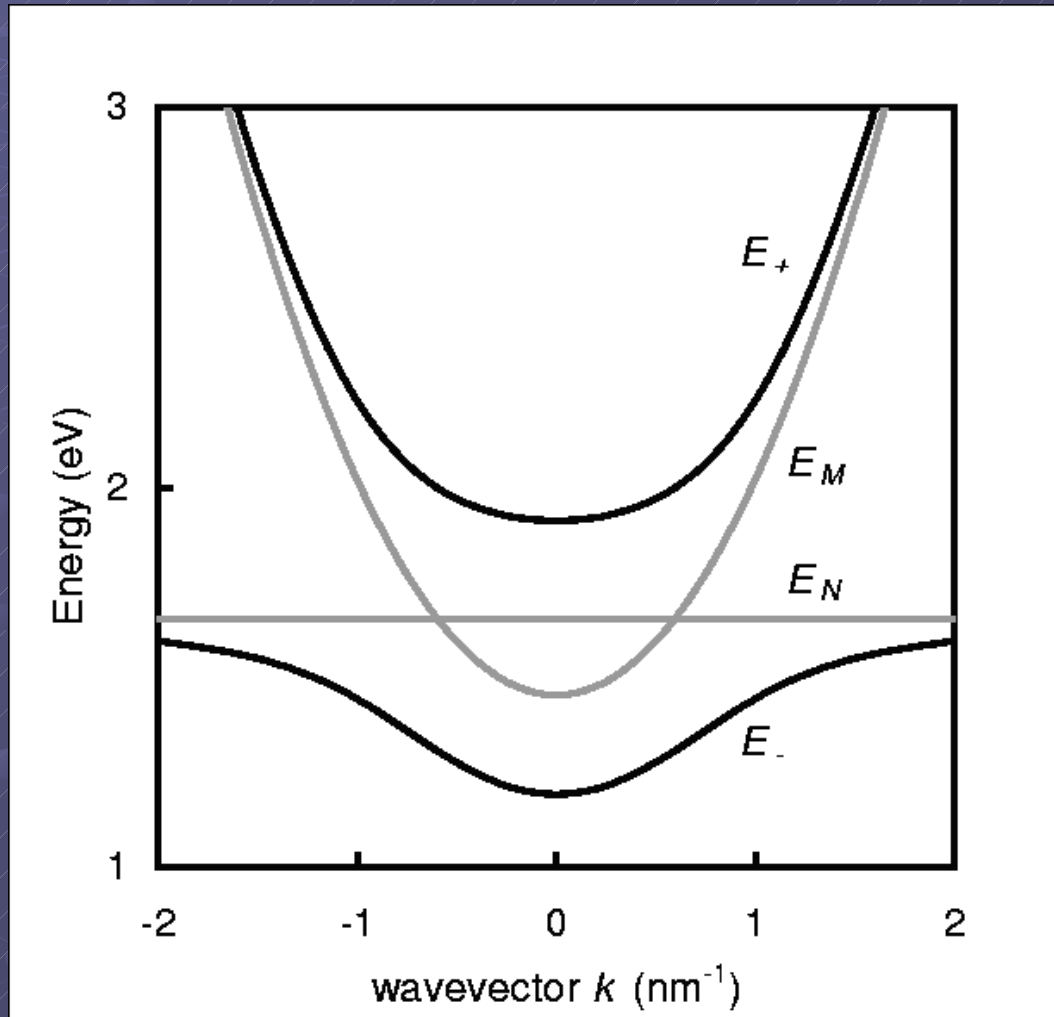
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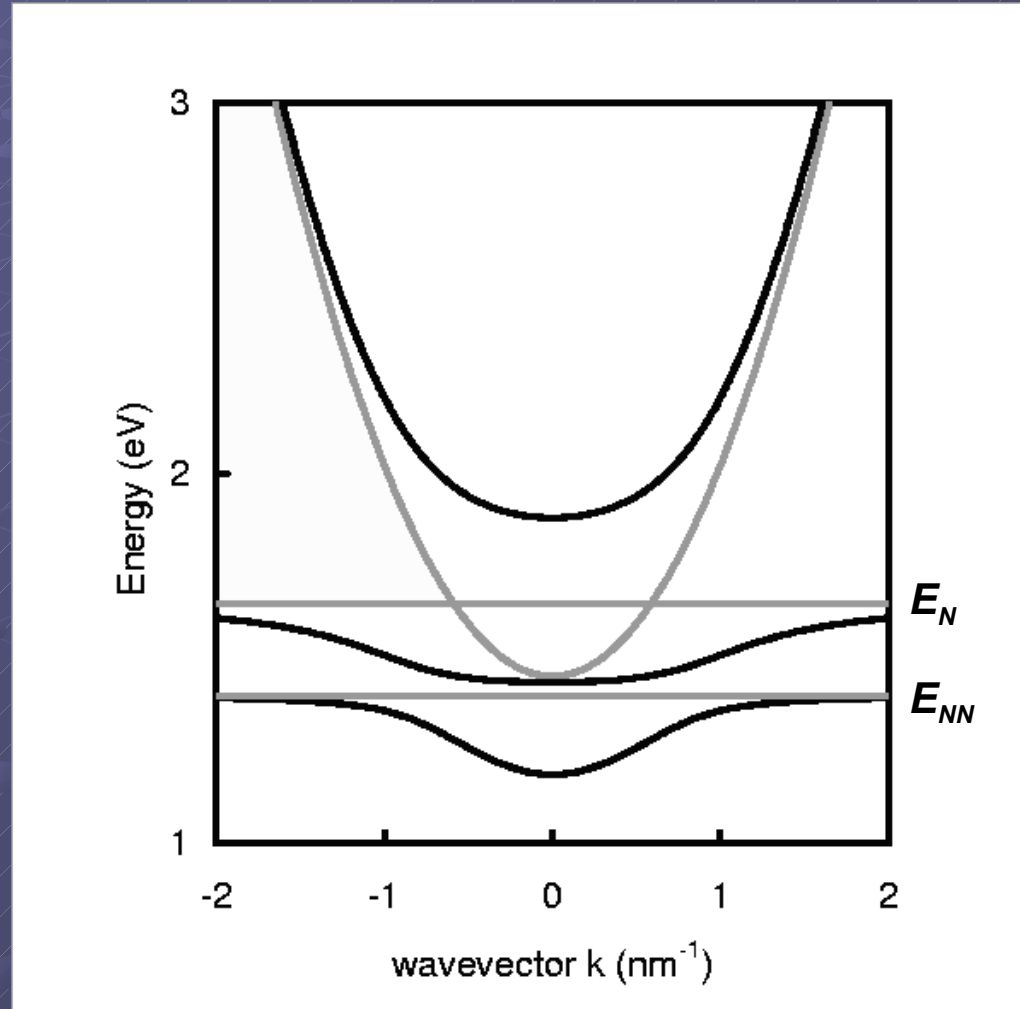
# Overview

- The interaction picture –  $n$ -band model
- Problem with the density of states
- The Anderson Hamiltonian
- The density of states
- Nitrogen scattering
- Mobility calculations

# Dispersion relations in the BAC model



# 3 band model<sup>[1]</sup>



[1] A. Lindsay, PhD Thesis, University of Surrey, (unpublished) (2002); S.B. Healy, A. Lindsay and E.P. O'Reilly, *IEE Proc.-Optoelectron.*, **151**, 397 (2004)



# Generalisation of the BAC model

' $n$ -band' model

$$H = \begin{bmatrix} E_M(\mathbf{k}) & V_1 x_1^{1/2} & V_2 x_2^{1/2} & \dots & V_{n-1} x_{n-1}^{1/2} \\ V_1 x_1^{1/2} & E_1 & 0 & \dots & 0 \\ V_2 x_2^{1/2} & 0 & E_2 & \dots & 0 \\ \vdots & \vdots & \vdots & \ddots & \vdots \\ V_{n-1} x_{n-1}^{1/2} & 0 & 0 & 0 & E_{n-1} \end{bmatrix}$$

Example: the 3-band model due to Lindsay <sup>[1]</sup> in terms of isolated nitrogen centres and N-N pairs

A more general model is given by the **LCINS** (linear combination of isolated nitrogen states) model, in which the nitrogen states are not assumed to be orthogonal. See, for instance, Lindsay and O'Reilly <sup>[2]</sup>.

[1] A. Lindsay, PhD Thesis, University of Surrey, (unpublished) (2002); S.B. Healy, A. Lindsay and E.P. O'Reilly, *IEE Proc.-Optoelectron.*, **151**, 397 (2004)

[2] A. Lindsay and E. P. O'Reilly, *Phys. Rev. Lett.*, **93**, 196402 (2004)

# Non-parabolicity

From the characteristic equation of the  $n$  – band Hamiltonian

$$E_M(\mathbf{k}) = \sum_i \frac{V_i^2 x_i}{E_i - E} + E \equiv \gamma(E)$$

**Note:** for any nitrogen energy  $E_i$

$$\text{As } E \rightarrow E_i, \gamma(E) \rightarrow \infty$$

Assuming  $E_M(\mathbf{k})$  is parabolic greatly simplifies the mathematics. (Note that  $m_0^*$  is the *matrix semiconductor effective mass*).

$$\frac{\hbar^2 k^2}{2m_0^*} = \gamma(E)$$

# Problem with the density of states (DOS)

From the dispersion relations, the densities of states are

$$N_{3D}(E) = \frac{(2m_0^*)^{3/2}}{4\pi^2\hbar^3} \gamma^{1/2}(E) \frac{d\gamma(E)}{dE}$$

and

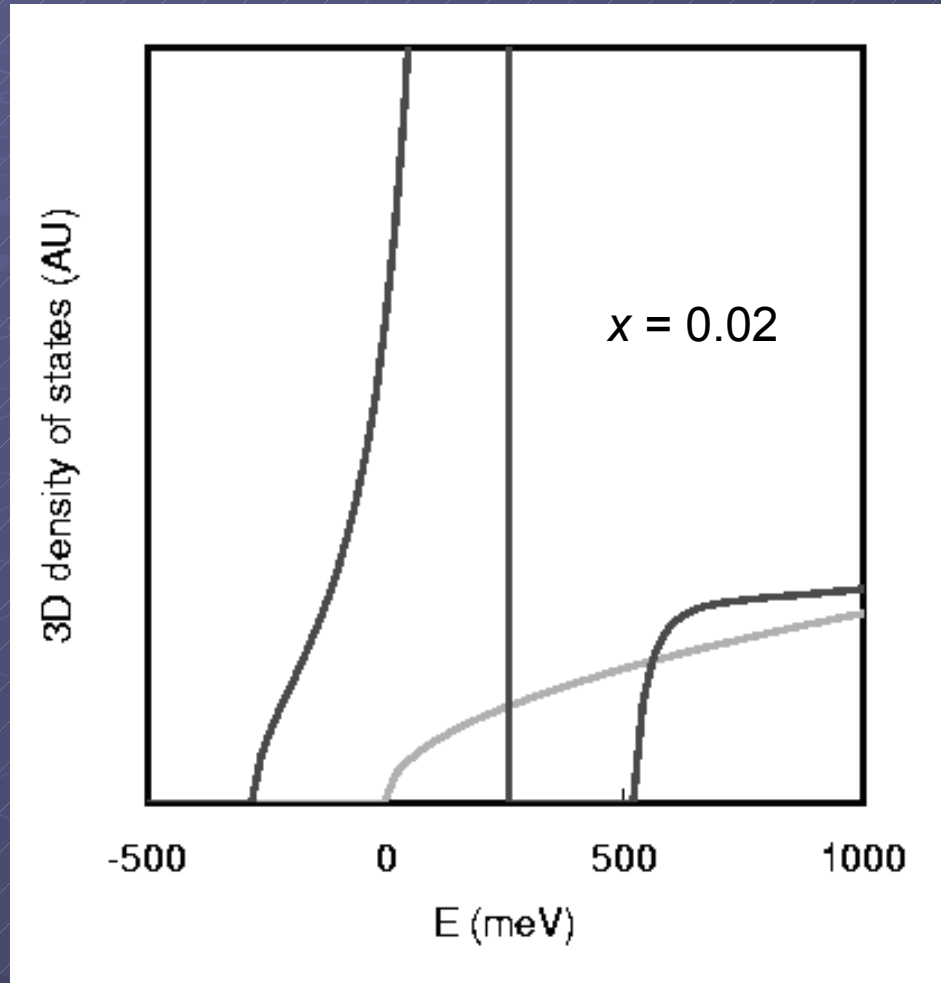
$$N_{2D}(E) = \frac{m_0^*}{2\pi\hbar^2} \frac{d\gamma(E)}{dE}$$

**But**

$$\begin{aligned} \text{number of states} < E_i &= \int_0^{E_i} \frac{(2m_0^*)^{3/2}}{4\pi^2\hbar^3} \gamma^{1/2}(E) \frac{d\gamma(E)}{dE} dE \\ &= \frac{2}{3} \frac{(2m_0^*)^{3/2}}{4\pi^2\hbar^3} \gamma^{3/2}(E_i) = \infty(!) \end{aligned}$$

with a similar problem in 2D.

# 3D DOS from dispersion relations



# Summary of problem

- The densities of states derived from the dispersion relations are non-integrable, implying an infinite number of states
- The singularities re-appear even when we relax the assumption of spherical energy bands
- Van Hove singularities *do not* make the DOS non-integrable



# The Anderson model <sup>[1]</sup>

$$H = H_0 + V$$

$H_0$  is a sum of two terms describing the energies of extended and localised states,

$$H_0 = \sum_{\mathbf{k}} E_{\mathbf{k}} b_{\mathbf{k}}^+ b_{\mathbf{k}} + \sum_{\mathbf{j}} E_{\mathbf{j}} b_{\mathbf{j}}^+ b_{\mathbf{j}} \quad V = \frac{1}{\sqrt{N_C}} \sum_{\mathbf{j}, \mathbf{k}} \left\{ e^{i\mathbf{k} \cdot \mathbf{j}} V_{\mathbf{kj}} b_{\mathbf{k}}^+ b_{\mathbf{j}} + e^{-i\mathbf{k} \cdot \mathbf{j}} V_{\mathbf{kj}}^* b_{\mathbf{j}}^+ b_{\mathbf{k}} \right\}$$

$N_C$  is the number of primitive cells in the crystal and the  $V_{\mathbf{kj}}$  characterise the hybridisation strength.

For a single impurity, the Green's function of the system has been found by Wu *et al* <sup>[2]</sup>

[1] P.W. Anderson, *Phys. Rev.*, **124**, 41 (1961);

[2] J. Wu, K.M. Yu and W. Walukiewicz, *IEE Proc.-Optoelectron.*, **151**, 460 (2004)



# The generalised Hamiltonian

We find the Green's function for many impurities to be

$$G_{\mathbf{k}\mathbf{k}} = \left\{ E - E_{\mathbf{k}} - \frac{1}{N_C} \sum_{\mathbf{j}} \frac{V_{\mathbf{j}}^2}{E - E_{\mathbf{j}} + i\Delta_{\mathbf{j}}} \right\}^{-1}$$

where the  $\Delta_{\mathbf{j}}$  are interpreted as energy broadenings on the  $\mathbf{j}$ th impurity. From the poles of  $G_{\mathbf{k}\mathbf{k}}$ , we can construct the generalised Hamiltonian

$$H = \begin{bmatrix} E_M(\mathbf{k}) & V_1/\sqrt{N_C} & V_2/\sqrt{N_C} & \cdots & V_{n-1}/\sqrt{N_C} \\ V_1/\sqrt{N_C} & E_1 - i\Delta_1 & 0 & \cdots & 0 \\ V_2/\sqrt{N_C} & 0 & E_2 - i\Delta_2 & \cdots & 0 \\ \vdots & \vdots & \vdots & \ddots & \vdots \\ V_{n-1}/\sqrt{N_C} & 0 & 0 & 0 & E_{n-1} - i\Delta_{n-1} \end{bmatrix}$$

This can be rendered in terms of concentrations by putting  $x_i = N_i/N_C$

# The DOS from the Green's function

Because of the relation between  $\text{Im } G_{\mathbf{k}\mathbf{k}}$  and the density matrix, the density of states can be found from

$$N(E) = -\frac{1}{\pi} \text{Im} \int G_{\mathbf{k}\mathbf{k}} N_0(E_{\mathbf{k}}) dE_{\mathbf{k}}$$

This gives

$$N_{3D}(E) = -\frac{(2m_0^*)^{3/2}}{4\pi^2 \hbar^3} \Omega(E) \left\{ 2 \left[ \Gamma^2(E) + \Omega^2(E) \right]^{1/2} - \Gamma(E) \right\}^{-1/2}$$

and

$$N_{2D}(E) = \frac{m_0^*}{2\pi \hbar^2} \sum_n \left\{ \frac{1}{2} - \frac{1}{\pi} \arctan \left( \frac{\Gamma(E) - E_n}{\Omega(E)} \right) \right\}$$

where

$$\Omega(E) = -\sum_j \frac{V_j^2 x_j \Delta_j}{(E - E_j)^2 + \Delta_j^2} \quad \text{and} \quad \Gamma(E) = E - \sum_j \frac{V_j^2 x_j (E - E_j)}{(E - E_j)^2 + \Delta_j^2}$$

# Limits as $\Delta \rightarrow 0$

As the broadenings  $\Delta_j \rightarrow 0$ ,  $\Omega(E) \rightarrow 0$  and  $\Gamma(E) \rightarrow \gamma(E)$ , so

$$-\frac{1}{\pi} \lim_{\Delta_j \rightarrow 0} \text{Im} G_{\mathbf{k}\mathbf{k}} = \frac{1}{\pi} \lim_{\Omega \rightarrow 0} \frac{\Omega(E)}{(\gamma(E) - E_M)^2 + \Omega^2(E)} = \delta(\gamma(E) - E_M)$$

giving the general result

$$N(E) = \int N_0(E_M) \delta(\gamma(E) - E_M) dE_M = N_0\{\gamma(E)\}$$

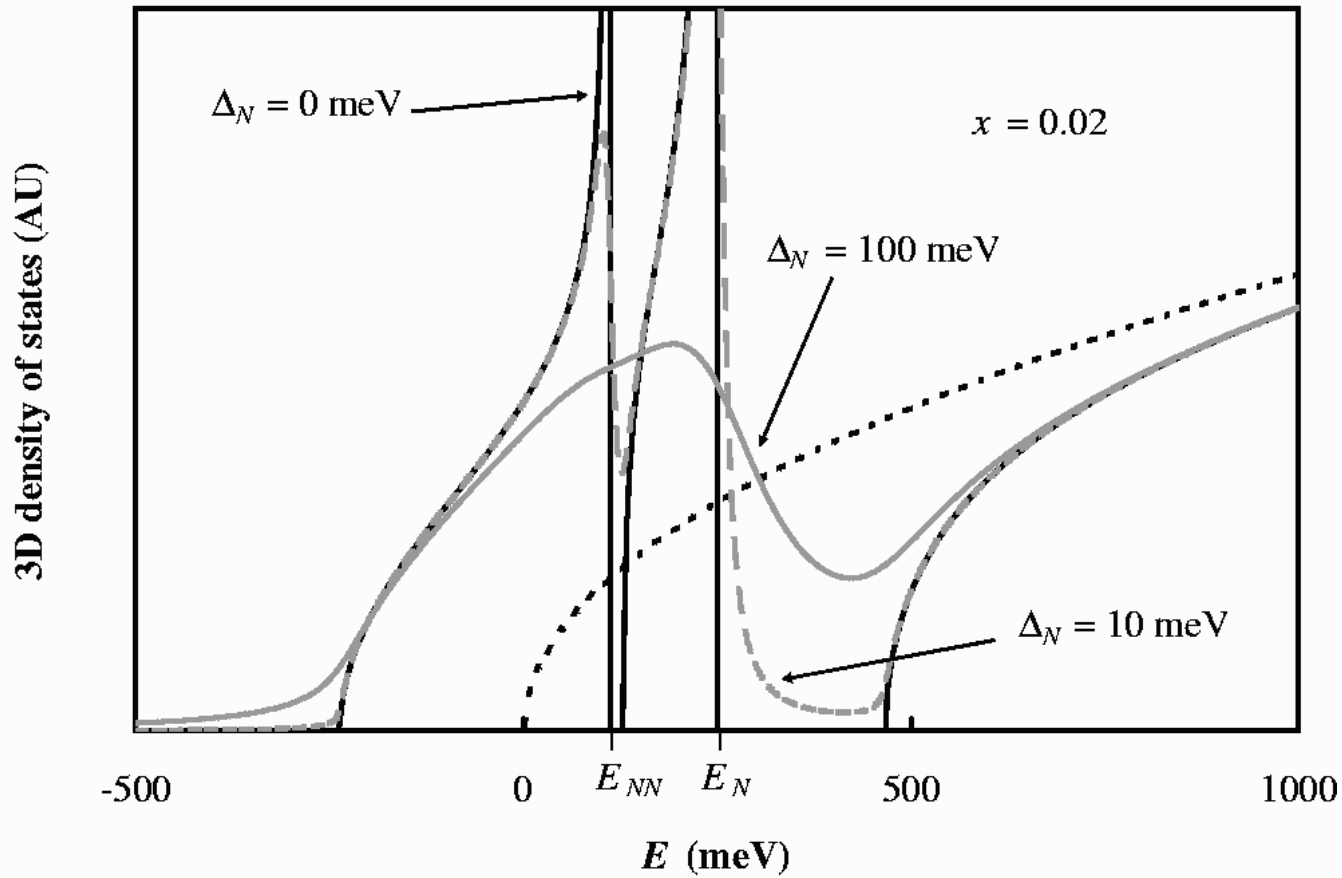
For the simplified model in which  $E_M$  is parabolic

$$\lim_{\Delta_j \rightarrow 0} N_{3D}(E) = \frac{(2m_0^*)^{3/2}}{4\pi^2 \square^3} \gamma^{1/2}(E)$$

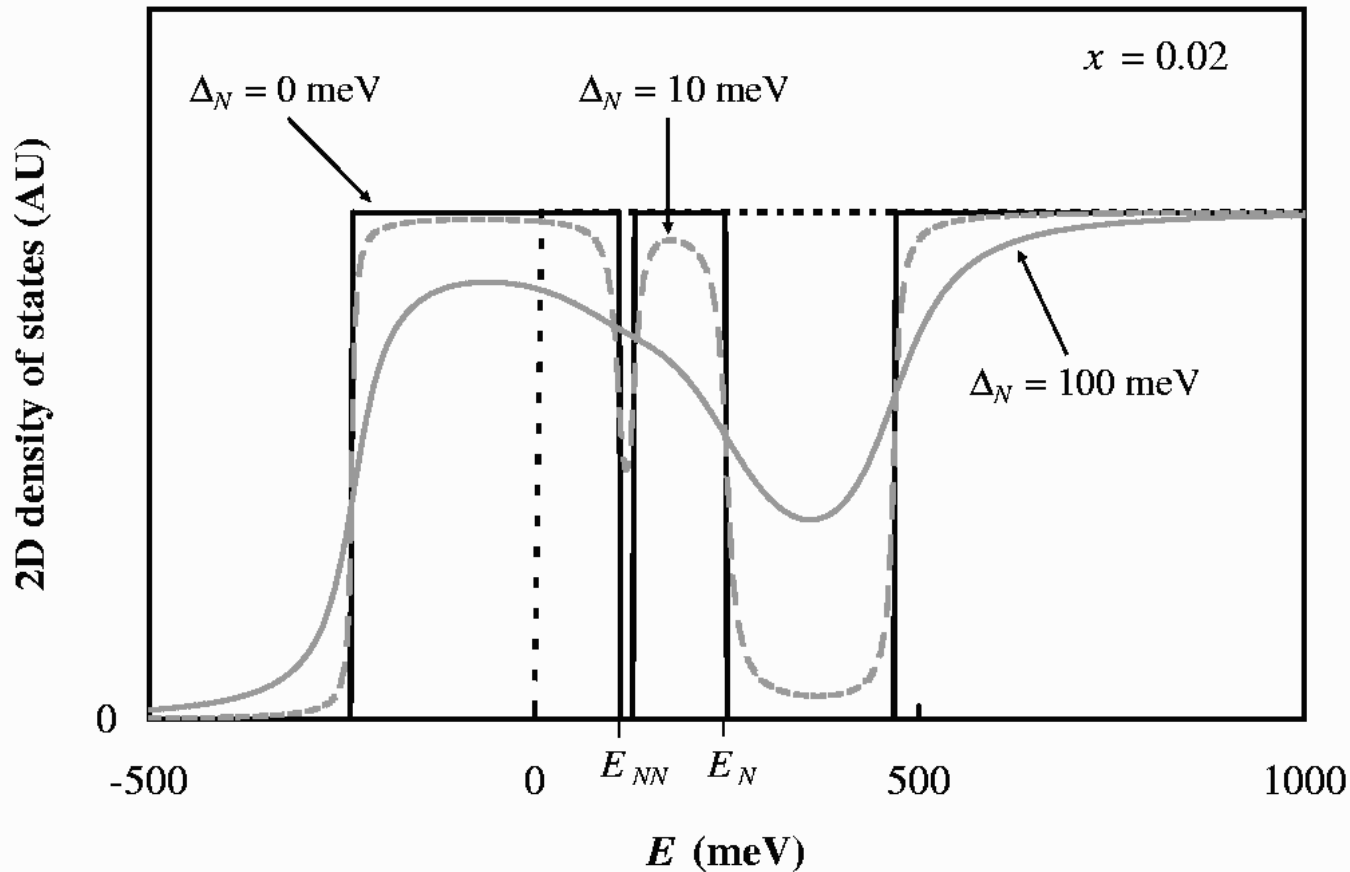
and

$$\lim_{\Delta_j \rightarrow 0} N_{2D}(E) = \frac{m_0^*}{2\pi \square^2} \sum_n \theta[\gamma(E) - E_n]$$

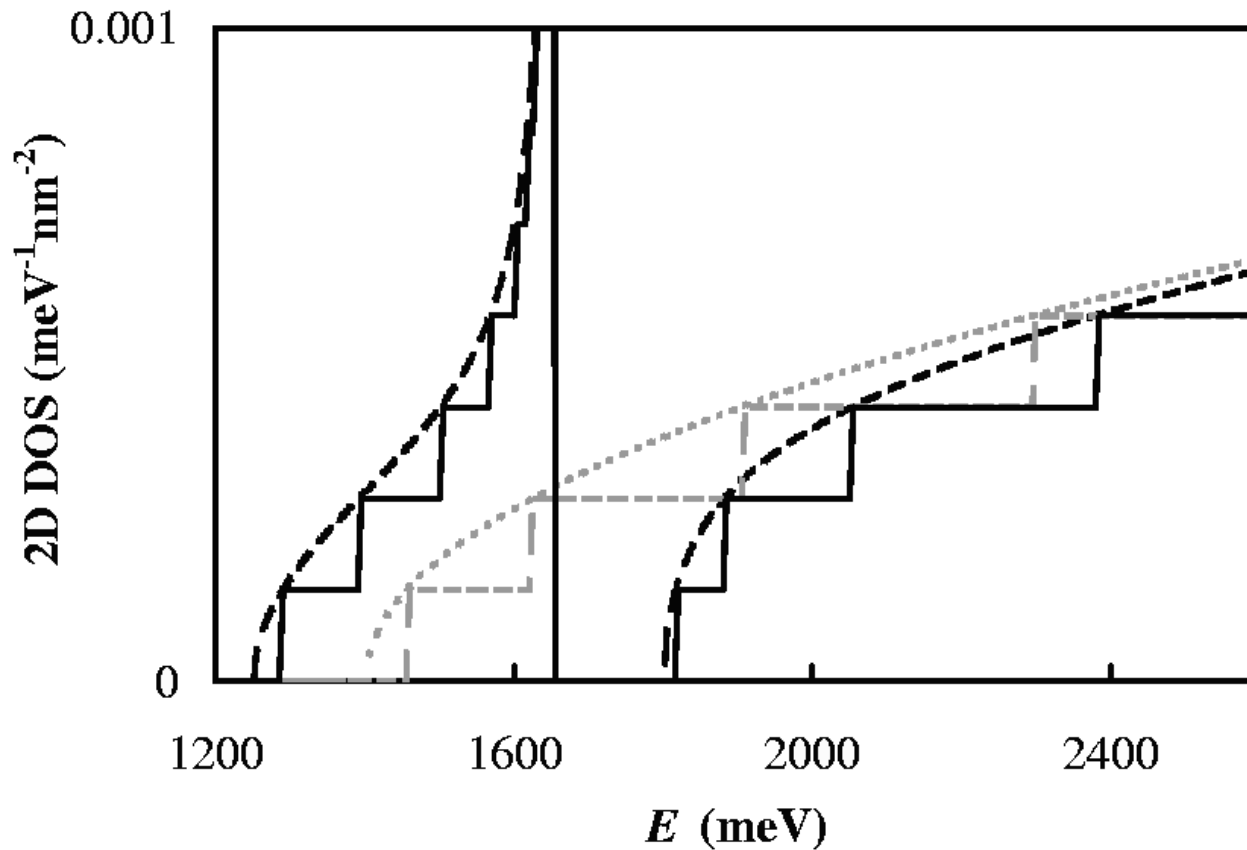
# The 3D density of states (3-band model)



# The 2D density of states in a single sub-band (3 – band model)

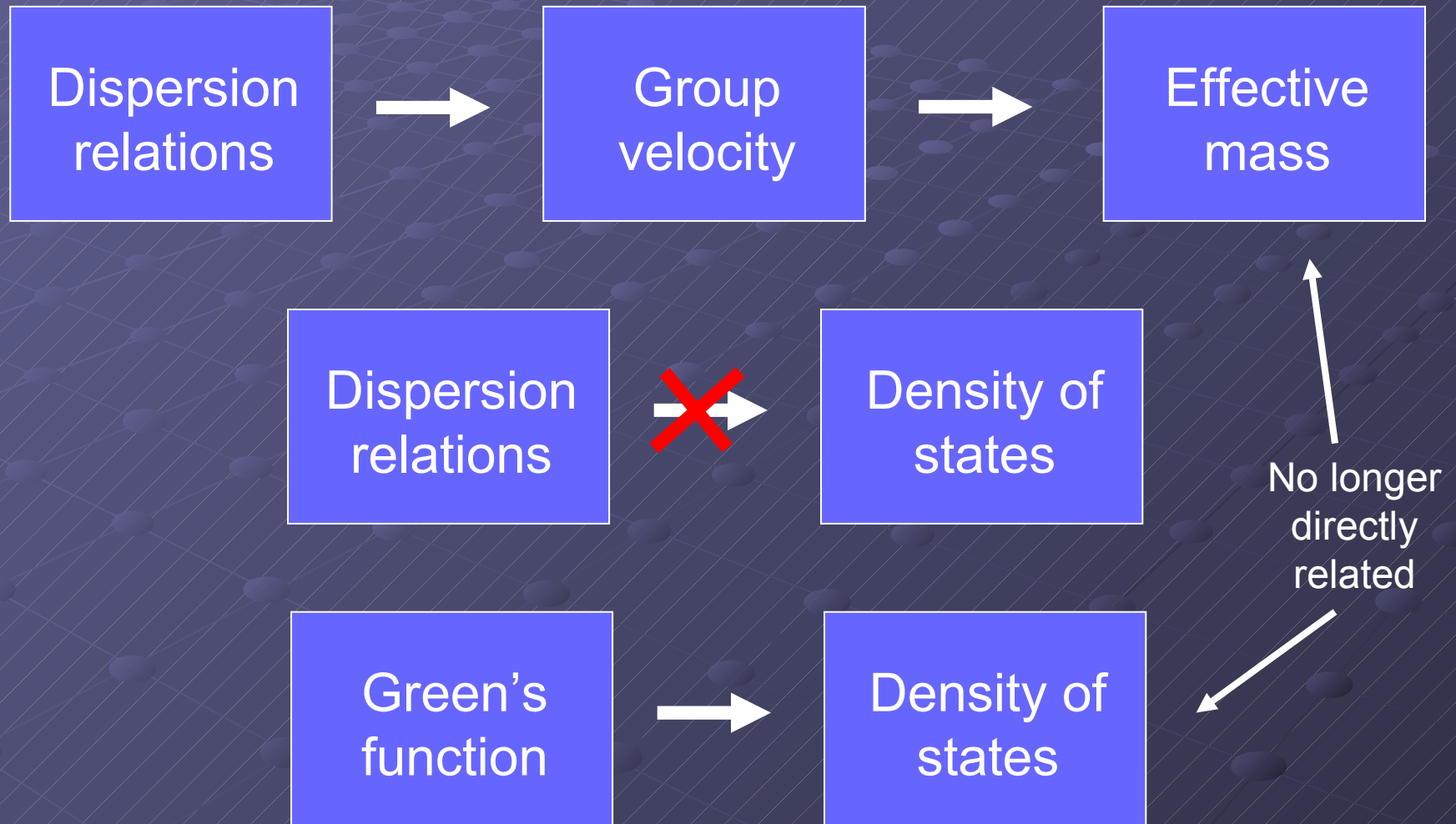


# The 2D density of states summed over sub-bands (2 – band model)





# A note on the effective mass



# The Green's function DOS

- The densities of states remain integrable
- The number of states in the system is conserved
- In the limit of zero energy broadening, we have a general procedure for finding the density of states from the density of states of the matrix semiconductor

# States of the system

The states of the system are a superposition of the host states and impurity states

$$|\psi_{\mathbf{k}}\rangle = \alpha_M |\phi_{\mathbf{k}}\rangle + \sum_{\mathbf{j}} \alpha_{\mathbf{j}} |\mathbf{j}\rangle$$

The fractional  $\Gamma$  character is

$$|\alpha_M|^2 = \left( \frac{1}{N_C} \sum_{\mathbf{j}} \frac{V_{\mathbf{j}}^2}{(E_{\mathbf{j}} - E)^2 + (\Delta_{\mathbf{j}} - \Delta(E))^2} + 1 \right)^{-1}$$

Note that

$$\lim_{\Delta_j \rightarrow 0} |\alpha_M|^2 = \left( \frac{d\gamma(E)}{dE} \right)^{-1}$$

The projection of the  $\mathbf{j}$ th impurity is

$$|\alpha_{\mathbf{j}}|^2 = \frac{|\alpha_M|^2}{N_C} \frac{V_{\mathbf{j}}^2}{(E - E_{\mathbf{j}})^2 + (\Delta(E) - \Delta_{\mathbf{j}})^2}$$

# Group velocity

The group velocity is given by

$$\mathbf{v}(\mathbf{k}) = \nabla_{\mathbf{k}} \omega = \frac{1}{\hbar} \nabla_{\mathbf{k}} E = \frac{1}{\hbar} \left( \frac{dE_M}{dE} \right)^{-1} \nabla_{\mathbf{k}} E_M$$

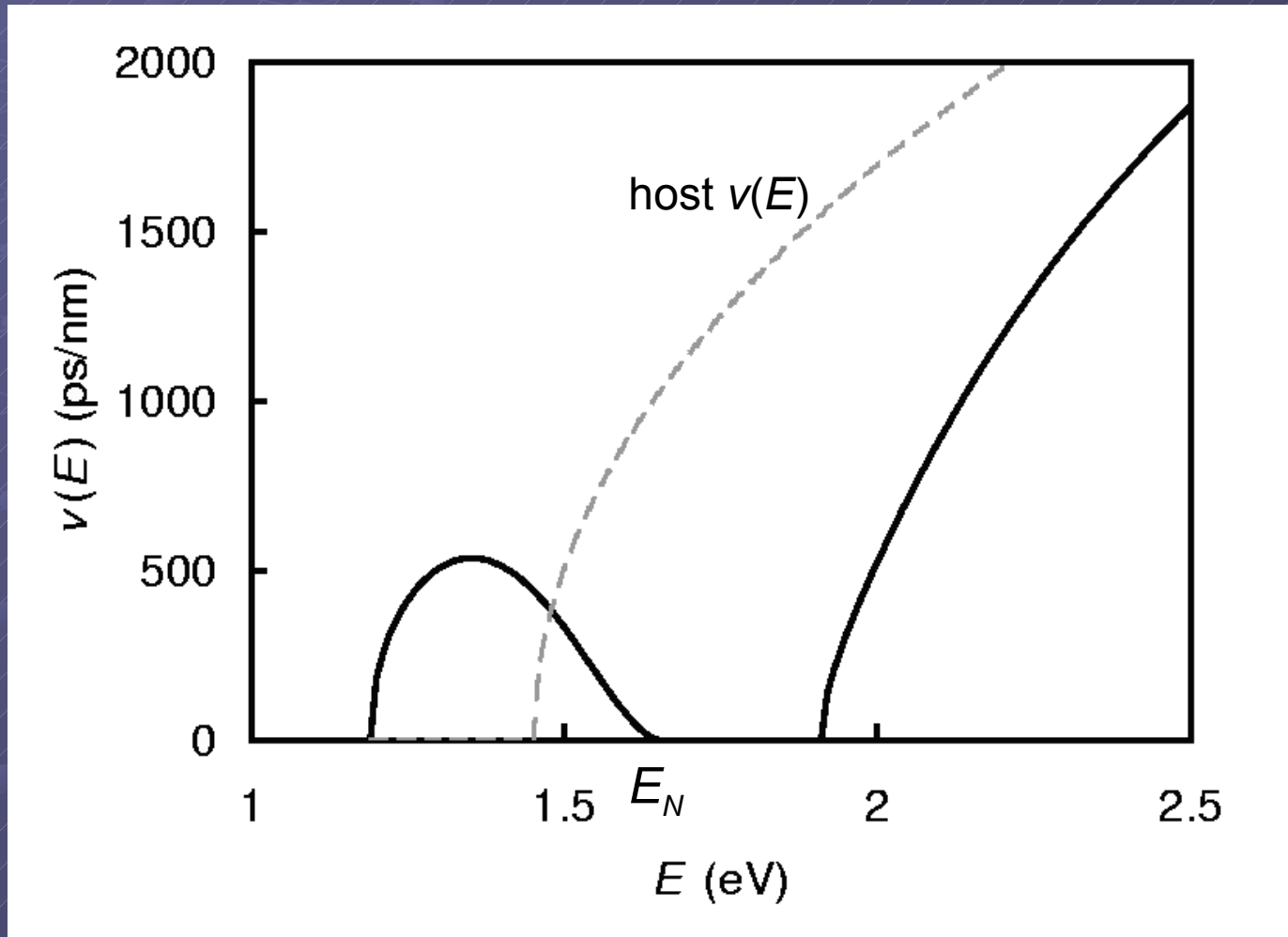
In terms of  $\gamma(E)$  the  $i$ th component of  $\mathbf{v}$  is

$$v_i(E) = \left( \frac{d\gamma(E)}{dE} \right)^{-1} v_i^0(\gamma(E)) = |\alpha_M|^2 v_i^0(\gamma(E))$$

Note that the effective mass in the dilute nitride is

$$m^* = \frac{d\gamma(E)}{dE} m_0^*$$

# Example: 2-band model with parabolic $E_M$



# S-matrix theory

S-matrix theory gives higher order results for scattering than Fermi's golden rule for scattering.

S-matrix theory was used by Fahy and O'Reilly<sup>[1]</sup> to develop a model of a scattering from a single isolated nitrogen impurity.

Later used by Fahy *et al*<sup>[2]</sup> to develop a model of resonant scattering in conjunction with the LCINS model.

[1] S. Fahy and E.P. O'Reilly, *Appl. Phys. Lett*, **83**, 3731 (2003); S. Fahy and E.P. O'Reilly, *Physica E*, **21**, 881 (2004)

[2] S. Fahy, A. Lindsay, H. Ouerdane and E. P. O'Reilly, *Phys. Rev. B*, **74**, 035203 (2006)



# The $S$ -matrix element

The  $S$ -matrix is

$$S(k, k) = \langle \mathbf{k} | V | \psi(\mathbf{k}) \rangle$$

so, in this model

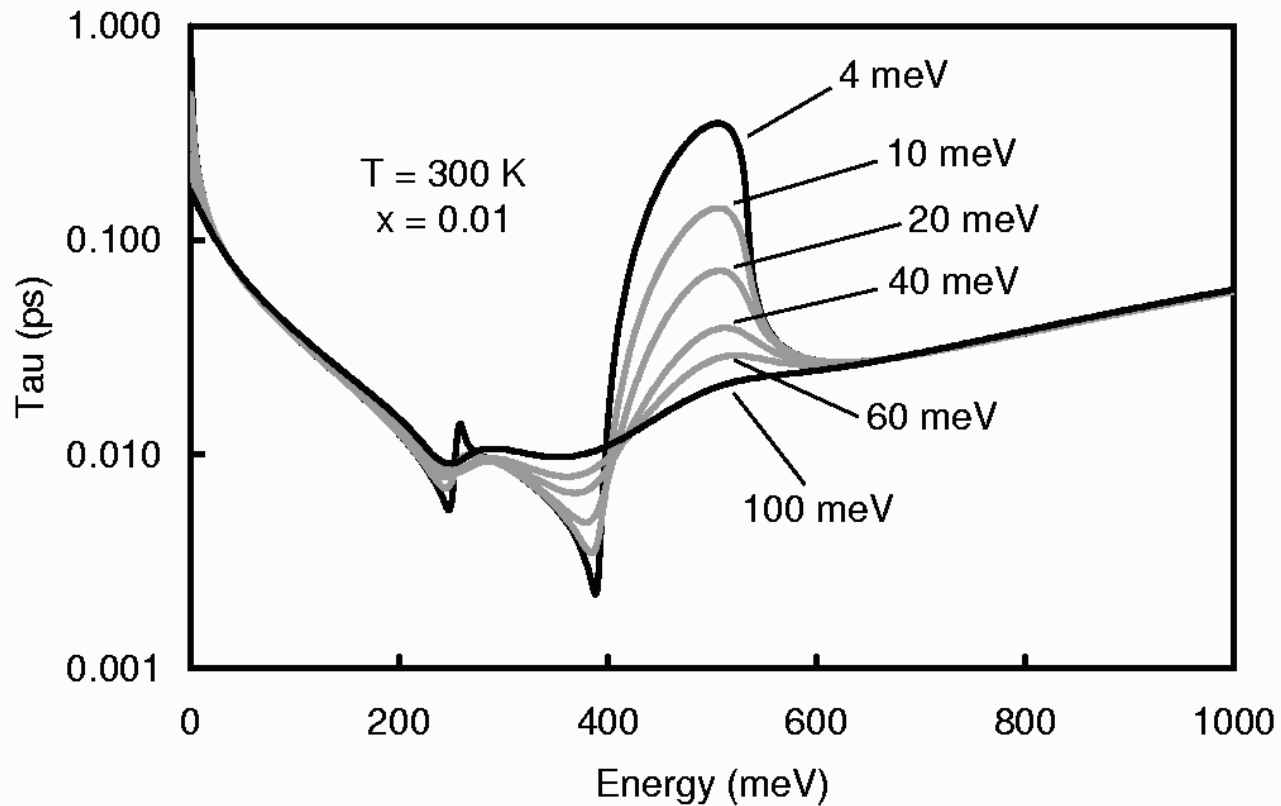
$$|S(k, k)|^2 = \sum_j \frac{V_j^2}{N_C} |\alpha_j|^2 + \text{interference terms}$$

We argue that the interference terms are due to random phases on the  $V_j$  and  $\alpha_j$  which tend to cancel out.

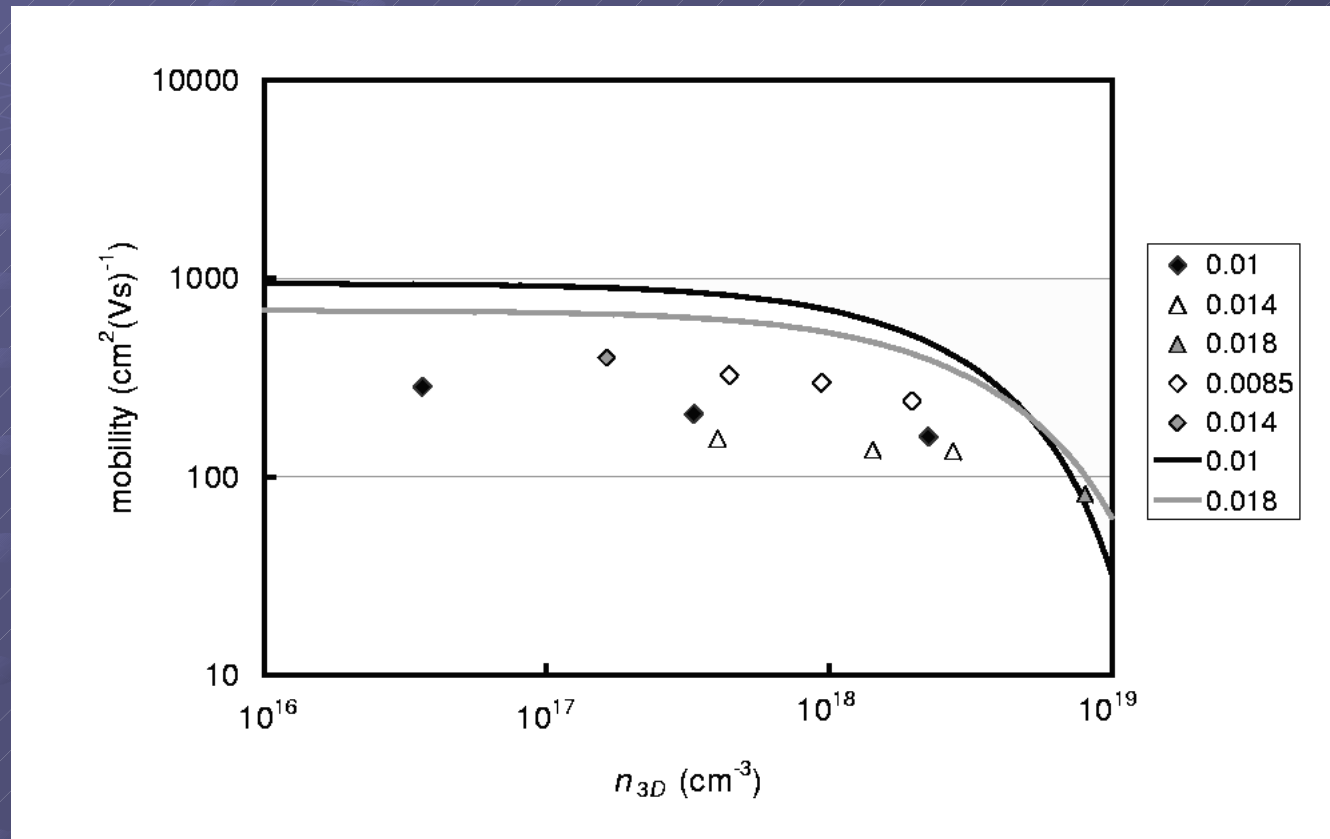
The scattering rate is then the result for independent scattering centres:

$$w(E) = \frac{\pi}{2\pi} a_0^3 |\alpha_M|^2 \sum_j \frac{V_j^4 x_j}{(E - E_j)^2 + (\Delta(E) - \Delta_j)^2} N(E)$$

# The relaxation time



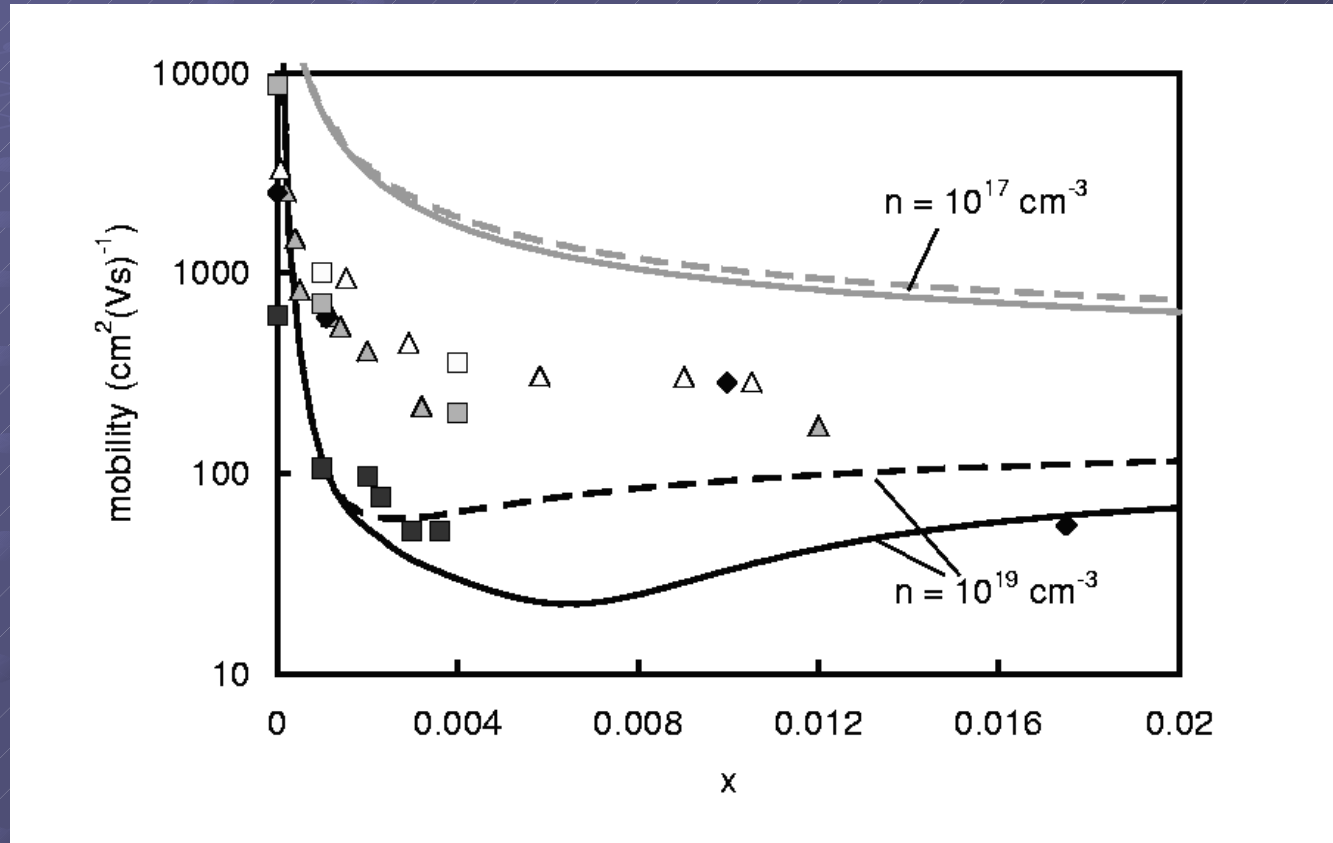
# Mobility v carrier density



Data points: R. Mouillet, PhD thesis, *l'Université Paris V1* (2004)

Drop in mobility at high carrier concentrations due to Fermi energy coming close to nitrogen impurity energies where the fractional  $\Gamma$  character is greatly reduced.

# Mobility v nitrogen concentration



D. Fowler *et al*, *AIP Conference Proceedings*, **772**, 497 (2005)



R. Mouillet, PhD thesis, *l'Université Paris V1* (2004)



E. Strohm, MSc thesis, *University of British Columbia* (2002)

# Summary

- An  $n$ -band model can be derived from the Green's function of the Anderson Hamiltonian
- A well-behaved density of states can be found from the imaginary part of the Green's function
- The scattering rate can be found from S-matrix theory
- Model calculations for the highly degenerate case show reasonable agreement with experiment

# Acknowledgements

Supervisors: Prof Brian Ridley and Prof Naci Balkan

Thanks also to

Dr Amelia Patanè for providing mobility measurements by Fowler *et al* <sup>[1]</sup>

Prof Eoin O'Reilly for providing a proof copy of Fahy *et al* <sup>[2]</sup>

This work has been supported by a grant from the Engineering and Physical Sciences Research Council.

[1] D. Fowler *et al*, *AIP Conference Proceedings*, **772**, 497 (2005)

[2] S. Fahy, A. Lindsay, H. Ouerdane and E. P. O'Reilly, *Phys. Rev. B*, **74**, 035203 (2006)